



AMP2017A SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Class AB linear LDMOS design
- Instantaneous wide bandwidth
- Rack mounted system
- Built-in protection circuits
- High reliability and ruggedness
- Suitable for all single channel modulation standards
- Designed for broadband EMI/RFI, Lab, communication applications



ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	380 - 1000 MHz	
Power Output @ Psat	60 Watt Min	CW
Power Output @ P1dB	50 Watt Min	
Power Gain	47 dB Min	
Power Gain Flatness	3.0 dB p-p Max	
Input Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	<-30 dBc Typ	38dBm/Tone, Δ = 1MHz
Harmonics	<-25 dBc Typ	At Rated Pout
Spurious	60 dBc Min	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	300 Watt Max	At rated Pout
Input Power Protection	+8 dBm Max	<10 Sec without damage
Load VSWR Protection	∞ : 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 562 mm	2U excluding handles
Weight	10 kg.	
RF Connectors In/Out	Type-N Female	Front or rear panel
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, USB Optional GPIB Interface	Optional Remote Bluetooth application

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OUTLINE DRAWING

